

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







2SC6096

ON Semiconductor®

http://onsemi.com

Bipolar Transistor 100V, 2A, Low VCE(sat), NPN Single PCP

Applications

DC / DC converter, relay drivers, lamp drivers, motor drivers, inverter

Features

- · Adoption of FBET, MBIT process
- Low collector-to-emitter saturation voltage
- · High allowable power dissipation

- · Large current capacity
- · High-speed switching
- · Halogen free compliance

Specifications

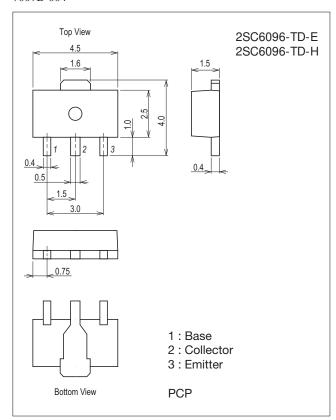
Absolute Maximum Ratings at Ta=25°C

| Parameter | Symbol | Conditions | Ratings | Unit |
|------------------------------|------------------|------------|---------|------|
| Collector-to-Base Voltage | V _{CBO} | | 120 | V |
| Collector-to-Emitter Voltage | VCES | | 120 | V |
| | VCEO | | 100 | V |
| Emitter-to-Base Voltage | VEBO | | 6.5 | V |
| Collector Current | IC | | 2 | Α |
| Collector Current (Pulse) | ICP | | 3 | Α |

Continued on next page.

Package Dimensions

unit: mm (typ) 7007B-004



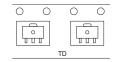
Product & Package Information

• Package : PCP

• JEITA, JEDEC : SC-62, SOT-89, TO-243

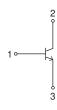
• Minimum Packing Quantity: 1,000 pcs./reel

Packing Type: TD Marking





Electrical Connection



Continued from preceding page.

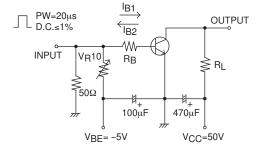
| Parameter | Symbol | Conditions | Ratings | Unit | |
|-----------------------|--------|---|-------------|------|--|
| Base Current | IB | | 400 | mA | |
| Collector Dissipation | P.O. | When mounted on ceramic substrate (250mm ² x0.8mm) | 1.3 | W | |
| | PC | Tc=25°C | 3.5 | | |
| Junction Temperature | Tj | | 150 | °C | |
| Storage Temperature | Tstg | | -55 to +150 | °C | |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Electrical Characteristics at Ta=25°C

| Parameter | Symbol | Conditions | | Ratings | | |
|---|-----------------------|---|-----|---------|-----|------------------|
| | Symbol | Conditions | min | typ | max | Unit μΑ μΑ |
| Collector Cutoff Current | ICBO | V _{CB} =80V, I _E =0A | | | 1 | μΑ |
| Emitter Cutoff Current | IEBO | V _{EB} =4V, I _C =0A | | | 1 | μΑ |
| DC Current Gain | hFE | V _{CE} =5V, I _C =100mA | 300 | | 600 | |
| Gain-Bandwidth Product | fŢ | V _{CE} =10V, I _C =300mA | | 300 | | MHz |
| Output Capacitance | Cob | V _{CB} =10V, f=1MHz | | 13 | | pF |
| Collector-to-Emitter Saturation Voltage | V _{CE} (sat) | I _C =1A, I _B =100mA | | 100 | 150 | mV |
| Base-to-Emitter Saturation Voltage | V _{BE} (sat) | I _C =1A, I _B =100mA | | 0.85 | 1.2 | V |
| Collector-to-Base Breakdown Voltage | V(BR)CBO | IC=10μA, IE=0A | 120 | | | V |
| Collector-to-Emitter Breakdown Voltage | V(BR)CES | I _C =100μA, R _{BE} =0Ω | 120 | | | V |
| | V(BR)CEO | IC=1mA, RBE=∞ | 100 | | | V |
| Emitter-to-Base Breakdown Voltage | V(BR)EBO | I _E =10μA, I _C =0A | 6.5 | | | V |
| Turn-ON Time | ton | | | 40 | | ns |
| Storage Time | t _{stg} | See specified Test Circuit. | | 1100 | | ns |
| Fall Time | tf | | | 40 | | ns |

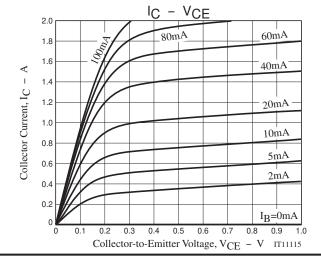
Switching Time Test Circuit

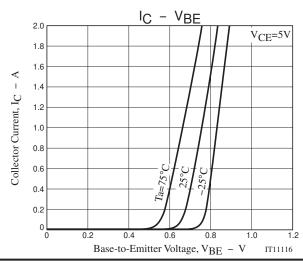


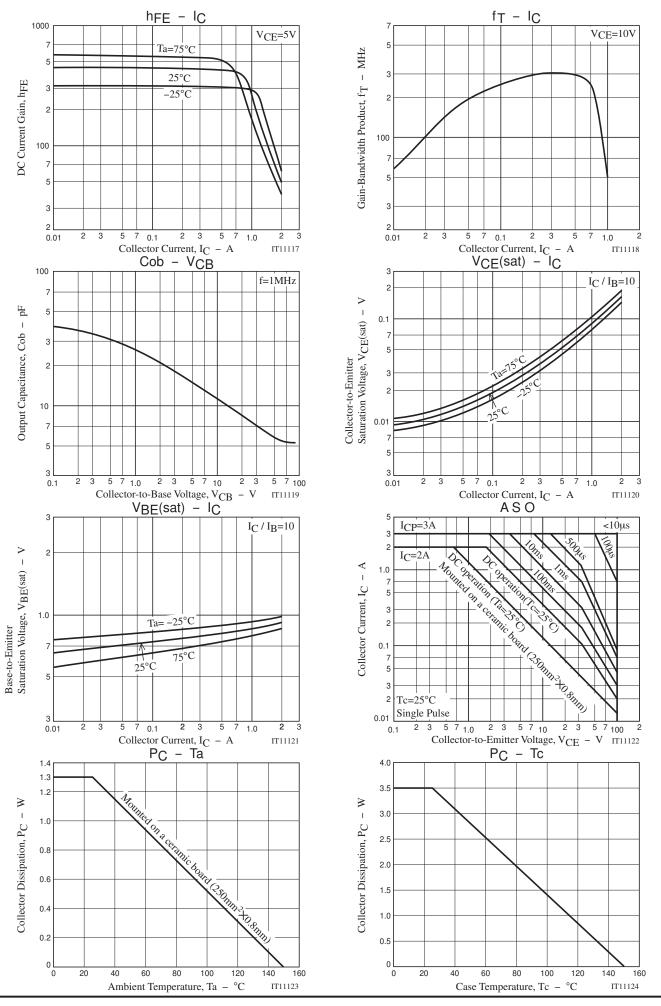
 $I_{C}=10I_{B1}=-10I_{B2}=0.5A$

Ordering Information

| Device | Package | Shipping | memo | |
|--------------|---------|----------------|--------------------------|--|
| 2SC6096-TD-E | PCP | 1,000pcs./reel | Pb Free | |
| 2SC6096-TD-H | PCP | 1,000pcs./reel | Pb Free and Halogen Free | |





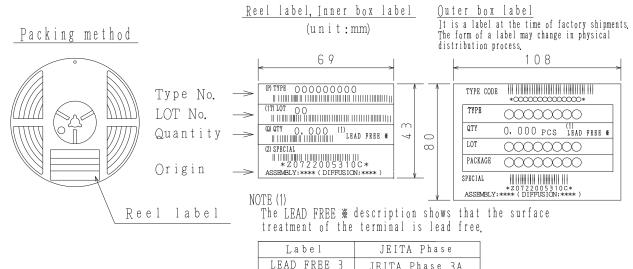


Embossed Taping Specification

2SC6096-TD-E, 2SC6096-TD-H

1. Packing Format

| Package Name | Carrier Tape | Maximum Number of devices contained (pcs) | | | Packing format | | |
|--------------|--------------|--|-----------|-----------|--------------------------|--------------------------|--|
| | Туре | Reel | Inner box | Outer box | Inner BOX (C-1) | Outer BOX (A-7) | |
| PCP | PCP | 1, 000 | 4,000 | 24,000 | 4 reels contained | 6 inner boxes contained | |
| | | | | | Dimensions:mm (external) | Dimensions:mm (external) | |
| | | | | | 183×72×185 | 440×195×210 | |

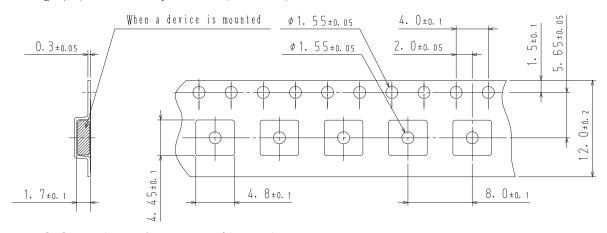


JEITA Phase 3A

JEITA Phase 3

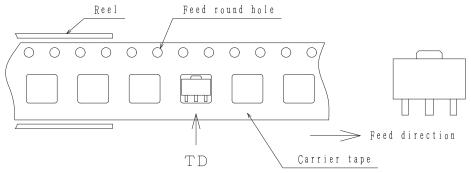
2. Taping configuration

2-1. Carrier tape size (unit:mm)



LEAD FREE 4

2-2. Device placement direction



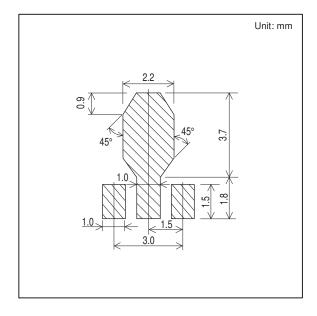
Those with pin 1 index on the feed hole side·····TD

Outline Drawing

2SC6096-TD-E, 2SC6096-TD-H

Mass (g) Unit 0.058 *For reference mm 4. 5±0. 1 1. 6±0. 2 _ 1.5±0.1_ 2. 5±0. 1 4. 0±0. 2 1. 0±0. 2 0. 4+0. 08 0. 4±0. 03 0. 5^{+0. 05} 1. 5±0. 2 3. O±0. 2 0. 75 0.10 *1:Lot indication

Land Pattern Example



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